TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIII)

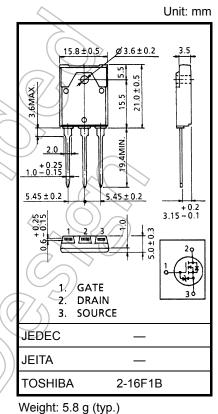
2SK3017

DC–DC Converter, Relay Drive and Motor Drive Applications

- Low drain-source ON resistance : $R_{DS (ON)} = 1.05 \Omega$ (typ.)
 - High forward transfer admittance $|Y_{fs}| = 7.0 \text{ S (typ.)}$
 - Low leakage current : $I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 720 \ V)$
- Enhancement mode : $V_{th} = 2.0$ to $4.0 \text{ V} (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	900	$\langle \mathbf{v} \rangle$
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	900	V
Gate-source voltage		V _{GSS}	±30	V
Drain current	DC (Note 1)	I _D	8.5	A
	Pulse (Note 1)	I _{DP}	25.5	А
Drain power dissipation	n (Tc = 25°C)	PD	90	W
Single pulse avalanche energy (Note 2)		E _{AS}	966	mJ
Avalanche current		I _{AR}) 8.5	Α
Repetitive avalanche energy (Note 3)		EAR	9	mJ
Channel temperature		Tch	150	°C
Storage temperature range		Tstg	-55 to 150	~c⁄



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch−c)}	1.39	°C / W
Thermal resistance, channel to ambient	R _{th (ch-a)}	41.6	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 24.5 mH, R_G = 25 Ω , I_{AR} = 8.5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

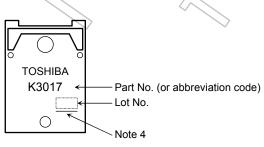
Electrical Characteristics (Ta = 25°C)

Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	urrent	I _{GSS}	V_{GS} = ±30 V, V_{DS} = 0 V	_	_	±10	μA
Gate-source bro	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30		_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V	X	_	100	μA
Drain-source br	reakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900	1	_	V
Gate threshold v	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0)/	4.0	V
Drain-source O	N resistance	R _{DS (ON)}	V _{GS} = 10 V, I _D = 4 A	77	1.05	1.25	Ω
Forward transfe	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 4 A	3.5	7.0	_	S
Input capacitance		C _{iss}			2150	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	35	_	pF
Output capacitance		Coss			220	1	
Switching time	Rise time	tr	$V_{GS} \stackrel{10 V}{}_{OV} \prod I \stackrel{I_D}{=} 4 A$	- (25	2^{1}	
	Turn-on time	t _{on}	$\begin{array}{c} \mathbf{CS} & 0 \mathbf{V} \mathbf{J} \mathbf{L} \\ 0 \\ \mathbf{C} \mathbf{F} \mathbf{F} \mathbf{F} \mathbf{F} \mathbf{F} \mathbf{F} \mathbf{F} F$	No the second se	60) _	ns
	Fall time	t _f	$\overrightarrow{V_{DD}} \doteq 400 \text{ V}$	$\langle n \rangle$	25		110
	Turn-off time	t _{off}	Duty $\leq 1\%$, t _w = 10 µs		120		
Total gate charg plus gate-drain)	je (Gate-source	Qg		_	70	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	_	37	_	nC
Gate-drain ("miller") charge		Q _{gd}		_	33	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	IDR		_	_	8.5	A
Pulse drain reverse current (Note 1)	I _{DRP}	<u> </u>			25.5	A
Forward voltage (diode)	V _{DSF}	I _{DR} = 8.5 A, V _{GS} = 0 V			-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 8.5 A, V _{GS} = 0 V		1300		ns
Reverse recovery charge	Qrr	dl _{DR} / dt = 100 A / μs	_	14.5	_	μC

Marking

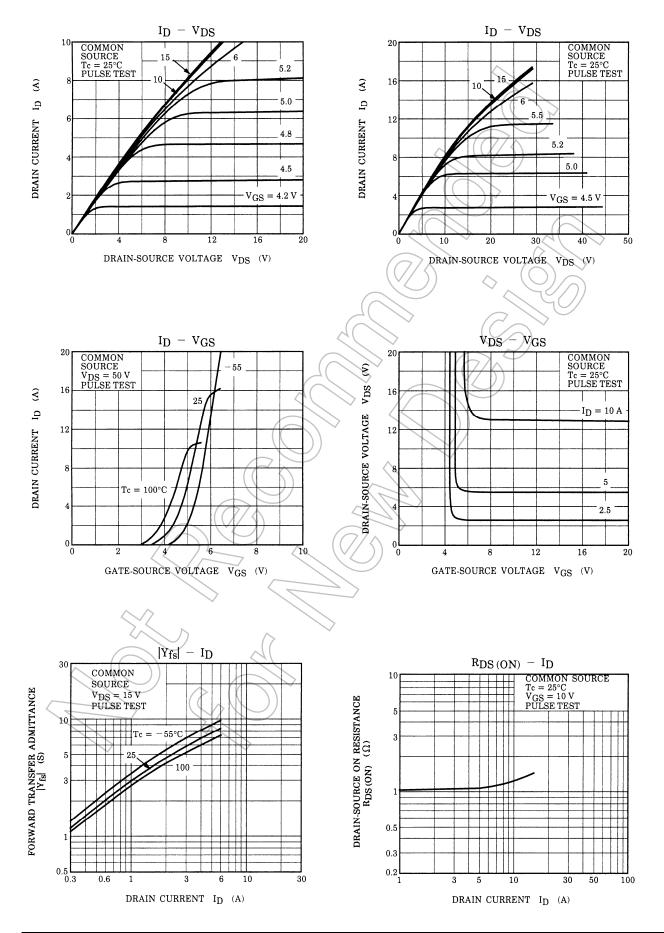


Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

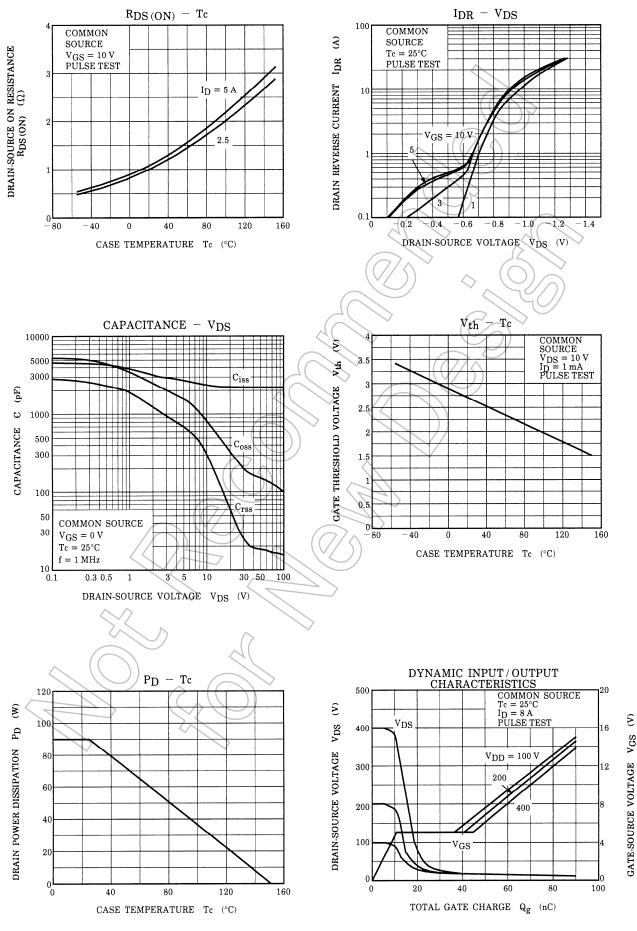
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

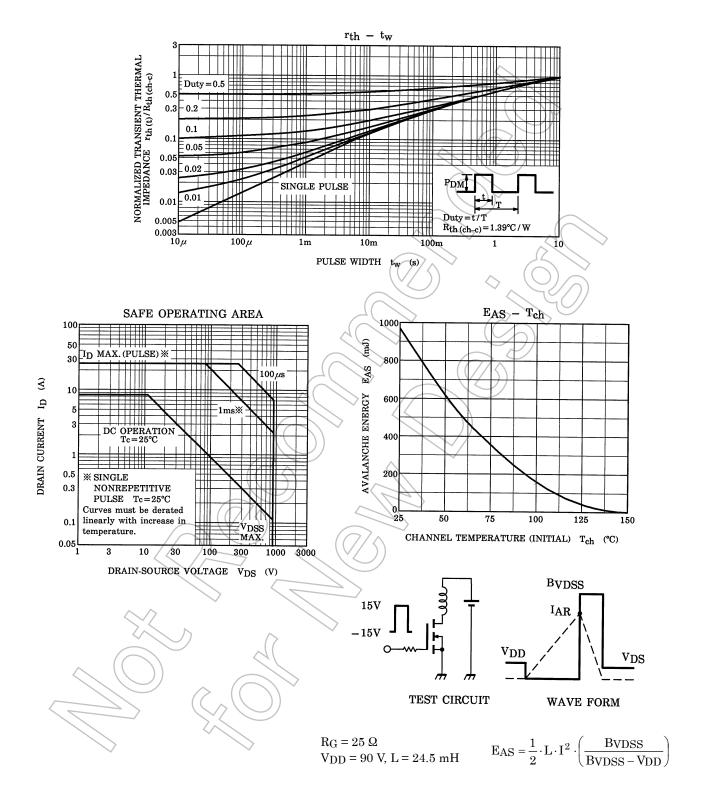
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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